

## Features

- $BV_{CE0} > -45V, -60V \text{ \& } -80V$
- $I_C = -1A$  Continuous Collector Current
- $I_{CM} = -2A$  Peak Pulse Current
- Low Saturation Voltage  $V_{CE(sat)} < -500mV @ -0.5A$
- Gain Groups 10 and 16
- Complementary NPN Types: BCX54, 55, and 56
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen- and Antimony-Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](mailto:contact@diodes.com) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>**

## Mechanical Data

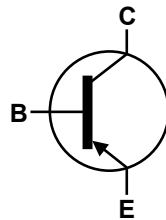
- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Leads; Solderable per MIL-STD-202 Method 208 <sup>(e3)</sup>
- Weight: 0.052 grams (Approximate)

## Applications

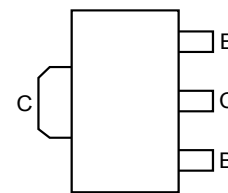
- Medium Power Switching or Amplification Applications
- AF Driver and Output Stages



Top View



Device Symbol

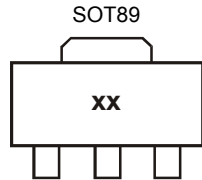

 Top View  
Pin-Out

## Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
BCX51TA	Standard	AA	7	12	1,000
BCX51-13R	Standard	AA	13	12	4,000
BCX5110TA	Standard	AC	7	12	1,000
BCX5116TA	Standard	AD	7	12	1,000
BCX5116TC	Standard	AD	13	12	4,000
BCX52TA	Standard	AE	7	12	1,000
BCX5210TA	Standard	AG	7	12	1,000
BCX5216TA	Standard	AM	7	12	1,000
BCX53TA	Standard	AH	7	12	1,000
BCX5310TA	Standard	AK	7	12	1,000
BCX5316TA	Standard	AL	7	12	1,000
BCX5316TC	Standard	AL	13	12	4,000
BCX5316-13R	Standard	AL	13	12	4,000
BCX5110TC	Standard	AC	13	12	4,000
BCX51TC	Standard	AA	13	12	4,000
BCX5210TC	Standard	AG	13	12	4,000
BCX5216TC	Standard	AM	13	12	4,000
BCX52TC	Standard	AE	13	12	4,000
BCX5310TC	Standard	AK	13	12	4,000
BCX53TC	Standard	AH	13	12	4,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information



xx = Product Type Marking Code, as follows:

BCX51 = AA	BCX52 = AE	BCX53 = AH
BCX5110 = AC	BCX5210 = AG	BCX5310 = AK
BCX5116 = AD	BCX5216 = AM	BCX5316 = AL

## Absolute Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	BCX51	BCX52	BCX53	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-45	-60	-100	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-45	-60	-80	V
Emitter-Base Voltage	V <sub>EBO</sub>		-5		V
Continuous Collector Current	I <sub>C</sub>		-1		A
Peak Pulse Collector Current (Single pulse)	I <sub>CM</sub>		-2		
Continuous Base Current	I <sub>B</sub>		-100		mA
Peak Pulse Base Current (Single pulse)	I <sub>BM</sub>		-200		

## Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

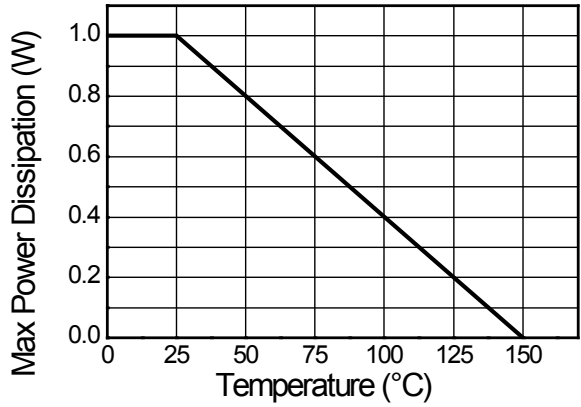
Characteristic	Symbol	Value	Unit
Power Dissipation	(Note 5)	1	W
	(Note 6)	1.5	
	(Note 7)	2.0	
Thermal Resistance, Junction to Ambient Air	(Note 5)	125	°C/W
	(Note 6)	83	
	(Note 7)	60	
Thermal Resistance, Junction to Lead	(Note 8) R <sub>θJL</sub>	13	°C/W
Thermal Resistance, Junction to Case	(Note 9) R <sub>θJC</sub>	27	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

## ESD Ratings (Note 10)

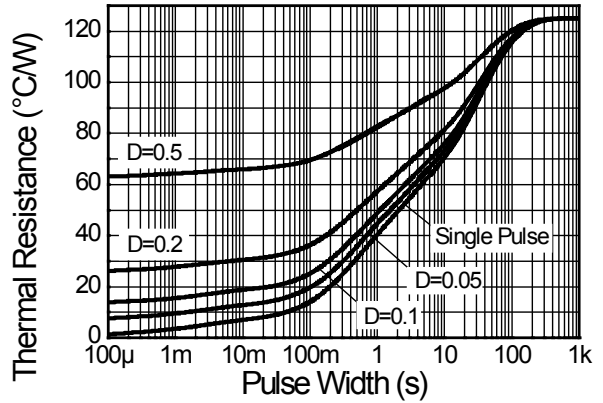
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
- For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
  - Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
  - Same as Note 5, except the device is mounted on 50mm x 50mm 1oz copper.
  - Thermal resistance from junction to solder-point (on the exposed collector pad).
  - Thermal resistance from junction to the top of the case.
  - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

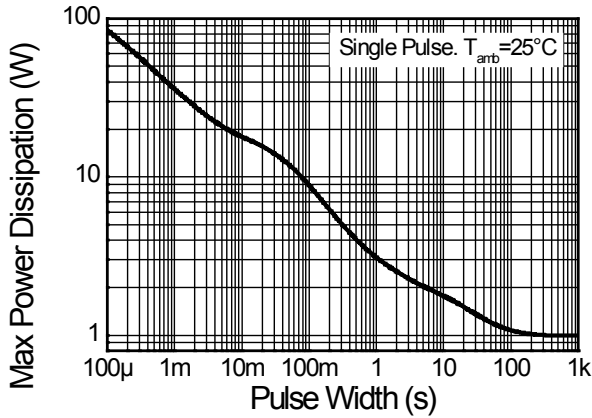
**Thermal Characteristics and Derating Information**



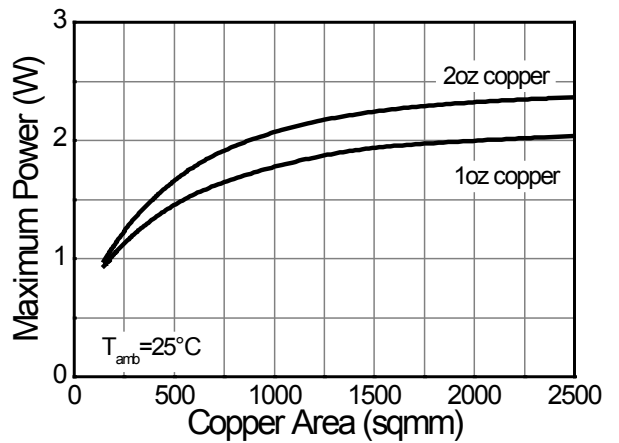
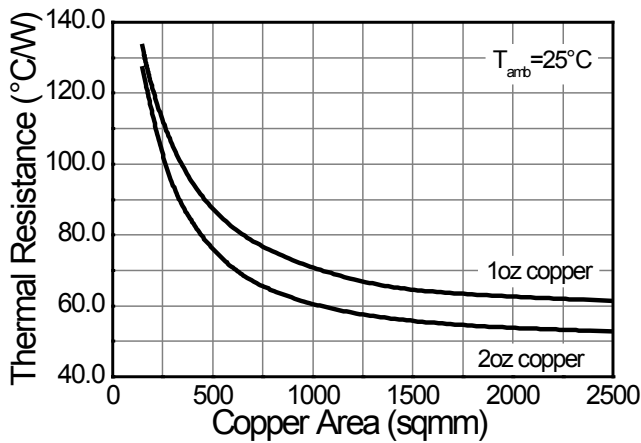
**Derating Curve**



**Transient Thermal Impedance**



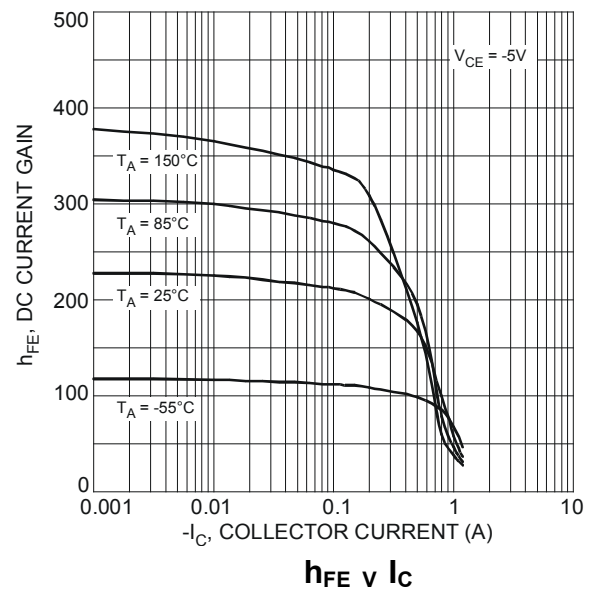
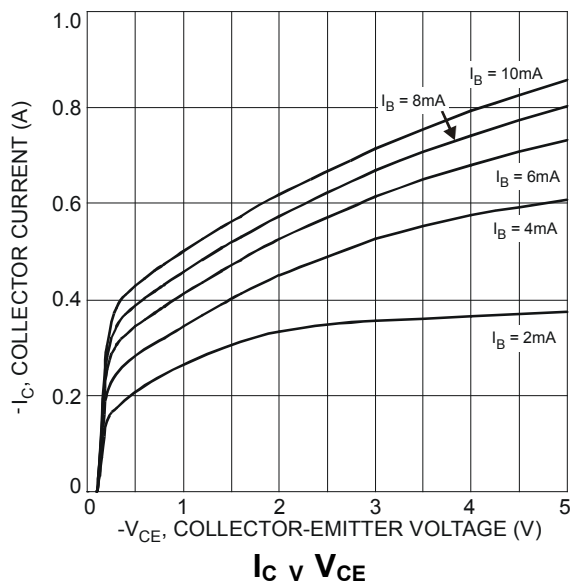
**Pulse Power Dissipation**



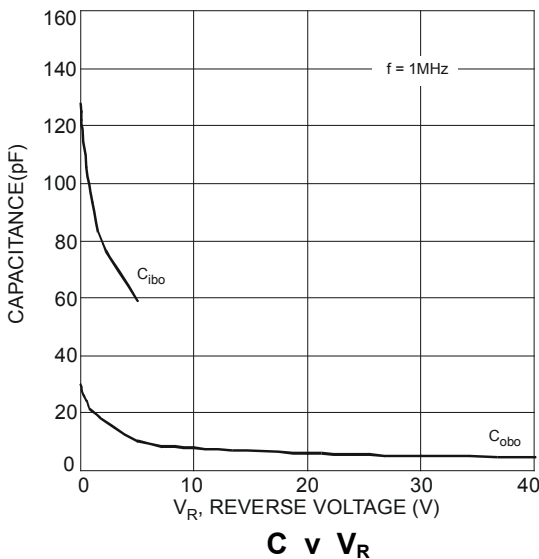
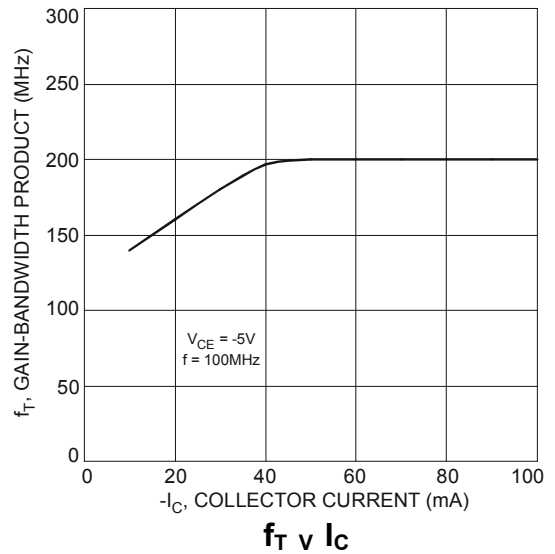
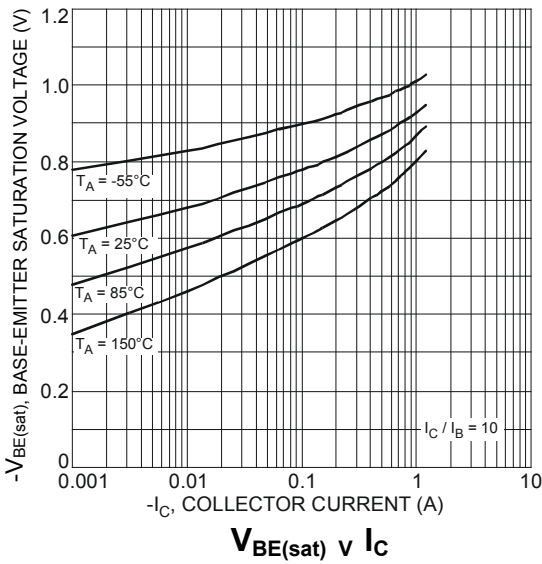
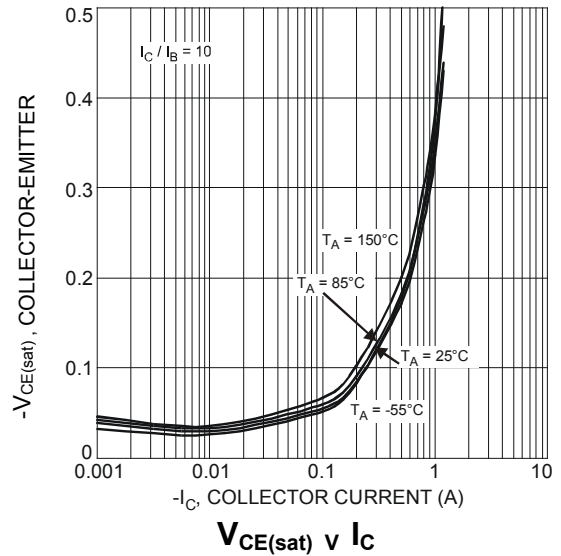
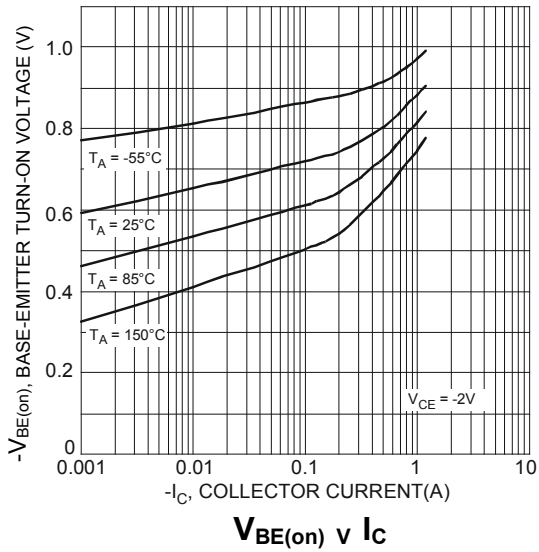
**Electrical Characteristics** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CB0</sub>	-45	—	—	V	I <sub>C</sub> = -100μA
		-60				
		-100				
Collector-Emitter Breakdown Voltage (Note 11)	BV <sub>CEO</sub>	-45	—	—	V	I <sub>C</sub> = -10mA
		-60				
		-80				
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-5	—	—	V	I <sub>E</sub> = -10μA
Collector Cut-Off Current	I <sub>CBO</sub>	—	—	-0.1 -20	μA	V <sub>CB</sub> = -30V V <sub>CB</sub> = -30V, T <sub>J</sub> = +150°C
Emitter Cut-Off Current	I <sub>EBO</sub>	—	—	-20	nA	V <sub>EB</sub> = -5V
DC Current Gain (Note 11)	h <sub>FE</sub>	25	—	—	—	I <sub>C</sub> = -5mA, V <sub>CE</sub> = -2V I <sub>C</sub> = -150mA, V <sub>CE</sub> = -2V I <sub>C</sub> = -500mA, V <sub>CE</sub> = -2V
		40				
		25				
		63				
	10 gain grp	63	—	160		I <sub>C</sub> = -150mA, V <sub>CE</sub> = -2V
	16 gain grp	100	—	250		I <sub>C</sub> = -150mA, V <sub>CE</sub> = -2V
Collector-Emitter Saturation Voltage (Note 11)	V <sub>CE(sat)</sub>	—	—	-0.5	V	I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
Base-Emitter Turn-On Voltage (Note 11)	V <sub>BE(on)</sub>	—	—	-1.0	V	I <sub>C</sub> = -500mA, V <sub>CE</sub> = -2V
Transition frequency	f <sub>T</sub>	150	—	—	MHz	I <sub>C</sub> = -50mA, V <sub>CE</sub> = -10V f = 100MHz
Output Capacitance	C <sub>obo</sub>	—	—	25	pF	V <sub>CB</sub> = -10V, f = 1MHz

Note: 11. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

**Typical Electrical Characteristics** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)


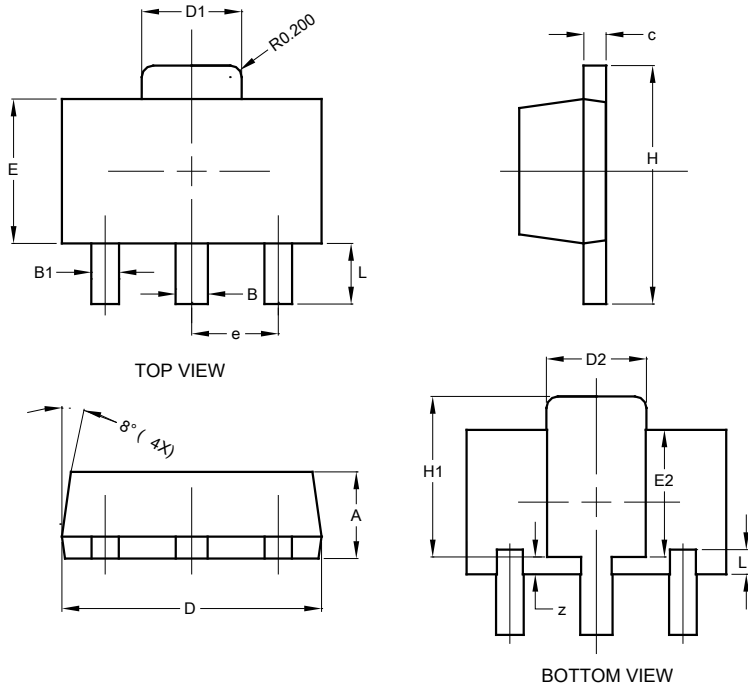
**Typical Electrical Characteristics** (continued.)



**Package Outline Dimensions**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT89**

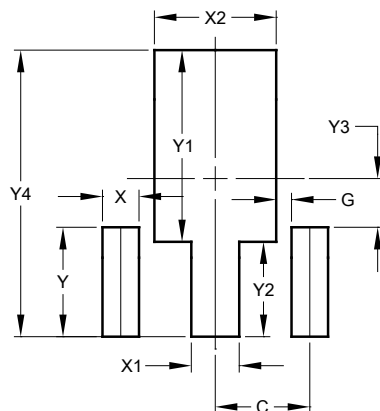


SOT89			
Dim	Min	Max	Typ
A	1.40	1.60	1.50
B	0.50	0.62	0.56
B1	0.42	0.54	0.48
c	0.35	0.43	0.38
D	4.40	4.60	4.50
D1	1.62	1.83	1.733
D2	1.61	1.81	1.71
E	2.40	2.60	2.50
E2	2.05	2.35	2.20
e	-	-	1.50
H	3.95	4.25	4.10
H1	2.63	2.93	2.78
L	0.90	1.20	1.05
L1	0.327	0.527	0.427
z	0.20	0.40	0.30
All Dimensions in mm			

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT89**



Dimensions	Value (in mm)
C	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530

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